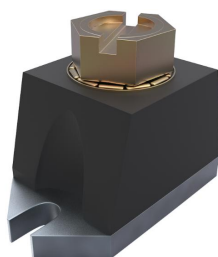


124NQ035/R-1 124NQ040/R-1 124NQ045/R-1 SCHOTTKY RECTIFIER



PRM1-1(HALF PAK Module)

Features

- 125°C T_J operation
- Unique high power, Half-Pak module
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-	35	V
Working Peak Reverse Voltage	V _{RWM}	-	40	
DC Blocking Voltage	V _R	-	45	
Average Forward Current	I _{F(AV)}	50% duty cycle @ T _C = 76°C, rectangular wave form	120	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	2880	A
Non-Repetitive Avalanche Energy	E _{AS}	T _J = 25°C, I _{AS} = 20A, L = 0.67mH	135	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. V _A = 1.5 × V _R typical	20	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 120A, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$ @ 240A, Pulse, $T_J = 25\text{ }^{\circ}\text{C}$	0.49 -	0.54 0.71	V
	V_{F2}	@ 120A, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$ @ 240A, Pulse, $T_J = 125\text{ }^{\circ}\text{C}$	0.43 -	0.52 0.71	V
Reverse Current*	I_{R1}	@ V_R = rated V_R , $T_J = 25\text{ }^{\circ}\text{C}$	4	10	mA
	I_{R2}	@ V_R = rated V_R , $T_J = 125\text{ }^{\circ}\text{C}$	1000	1200	mA
Junction Capacitance	C_T	@ $V_R = 5\text{V}$, $T_C = 25\text{ }^{\circ}\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	4300	5200	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/ μs

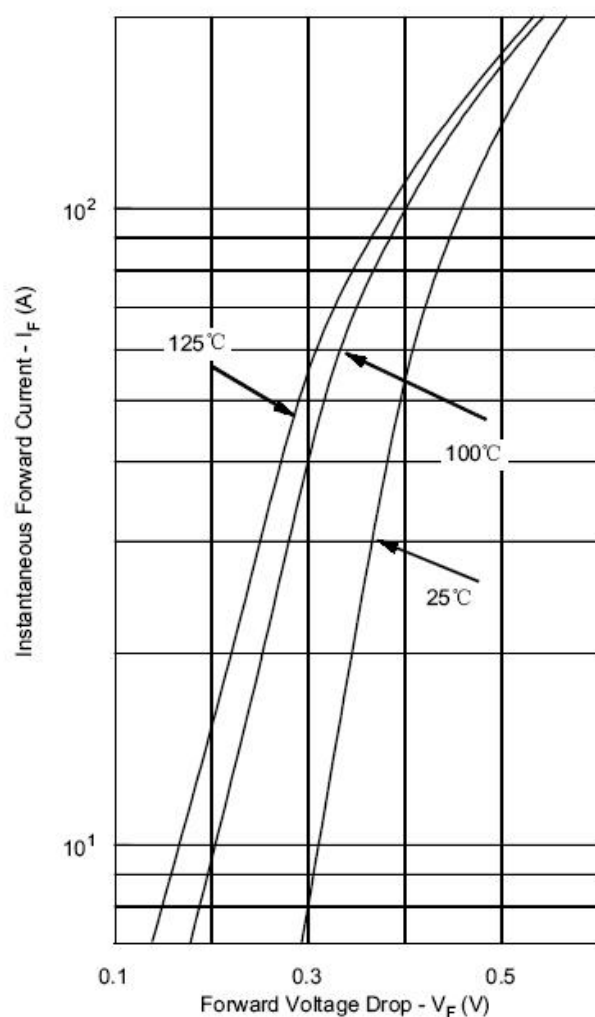
* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

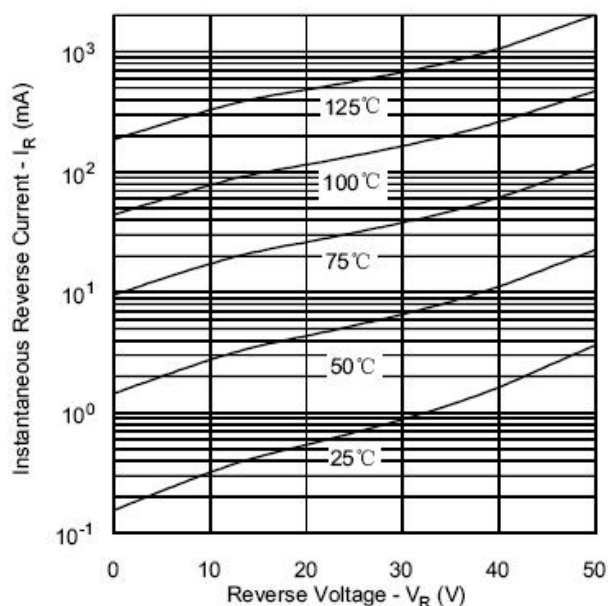
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	T _J	-	-55 to +125		°C
Storage Temperature	T _{stg}	-	-55 to +125		°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	0.40		°C/W
Typical Thermal Resistance, case to Heat Sink	R _{θcs}	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	T _M	Non-lubricated threads	Mounting Torque	23(min) 29(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

Ratings and Characteristics Curves

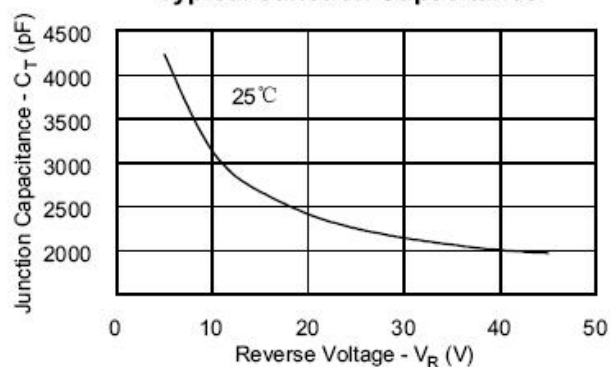
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



Ordering Information

Device	Package	Shipping
124NQ SERIES	PRM1-1(Pb-Free)	27pcs/ box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

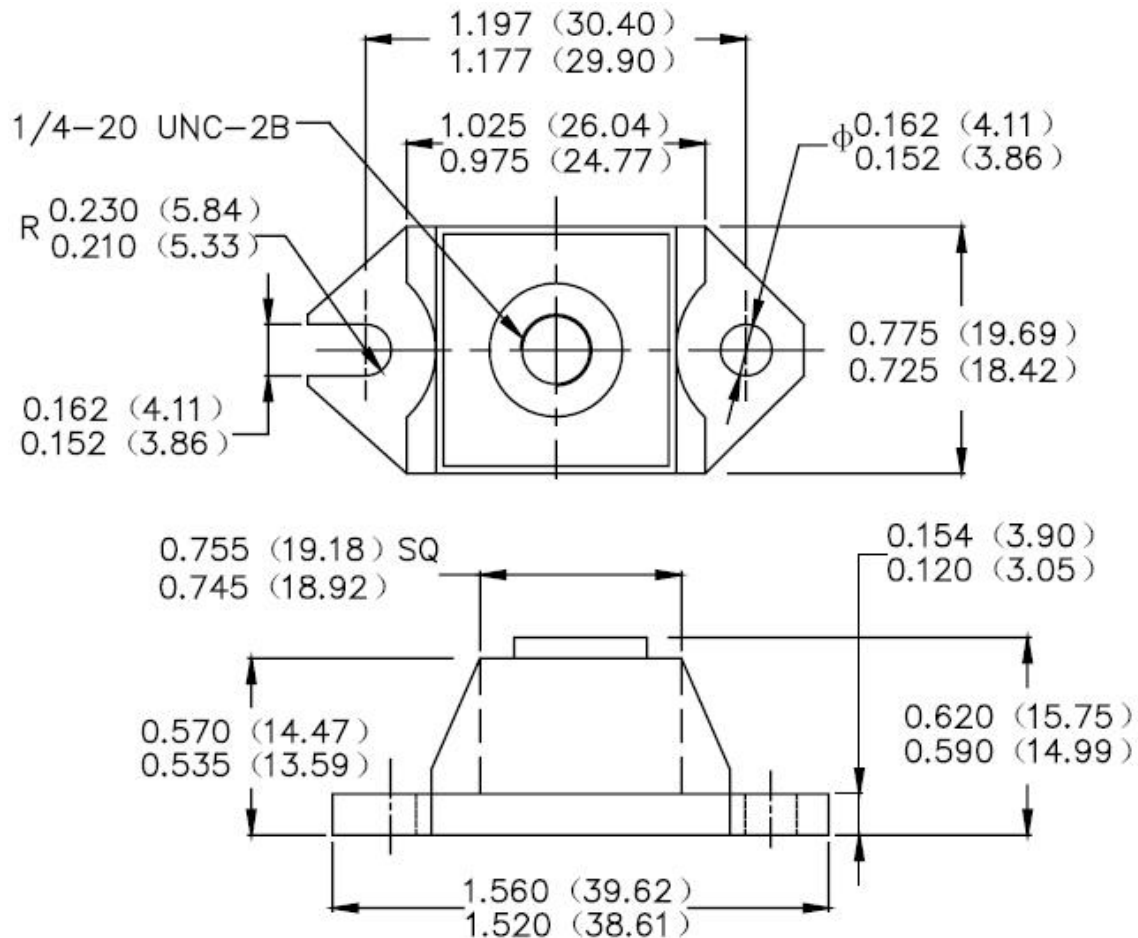


Where XXXX is YYWW

1st row SS YYWW
2nd row 124NQ035-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

Mechanical Dimensions PRM1-1 (Inches/Millimeters)



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